



## Characteristics

Parameter	Rating	Units
AC Operating Voltage	20-280	V <sub>AC</sub> (V <sub>rms</sub> )
Input Voltage Range	9-16	V
Load Current With 5°C/W Heat Sink	20	A <sub>rms</sub>
No Heat Sink	5	
On-State Voltage Drop	1.1	V <sub>P</sub> (at I <sub>L</sub> =2A <sub>P</sub> )
Blocking Voltage	800	V <sub>P</sub>
Thermal Resistance, Junction-to-Case, θ <sub>JC</sub>	0.35	°C/W

## Features

- Load Current up to 20A<sub>rms</sub> with 5°C/W Heat Sink
- 800V<sub>P</sub> Blocking Voltage  
Creepage Pin 1 to Pin 2 of 0.225 inch (5.715 mm)
- Zero-Cross Switching
- 2500V<sub>rms</sub> Isolation, Input to Output  
Creepage Pin 2 to Pin 3 of 0.375 inch (9.525 mm)
- DC Voltage Control, AC Output
- Optically Isolated
- Low EMI and RFI Generation
- High Noise Immunity
- Machine Insertable, Wave Solderable

## Applications

- Lighting
  - Tungsten Load: 4.75A (Free Air), 15A (Heat Sink)
  - Electrical Ballast: 5A (Free Air), 15A (Heat Sink)
- Programmable Controls
- Process Controls
- Power Control Panels
- Remote Switching
- Gas Pump Electronics
- Contactors
- Large Relays
- Solenoids
- Motors: 1/3HP (Free Air), 1/2HP (Heat Sink)
- Heaters

## Approvals

- UL 508 Recognized Component: File E69938  
See “**UL Approved Ratings**” on page 4.

## Description

CPC44055ST is a voltage-controlled AC Solid State Switch utilizing dual power SCR outputs. This device also includes zero-cross turn-on circuitry and is specified with an 800V<sub>P</sub> blocking voltage.

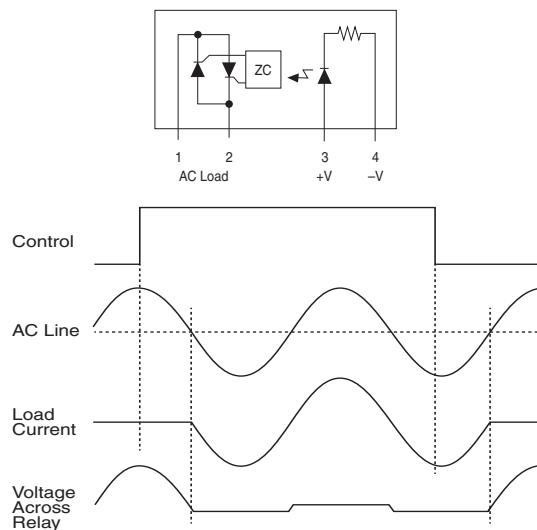
Tightly controlled zero-cross circuitry ensures low noise switching of AC loads by minimizing the generation of transients. The optically coupled input and output circuits provide exceptional noise immunity and 2500V<sub>rms</sub> of isolation. As a result, the CPC44055ST is well suited for industrial environments where electromagnetic interference would disrupt the operation of communications and control systems.

The unique SuperSIP package pioneered by IXYS Integrated Circuits Division allows Solid State Relays to achieve the highest load current currently available in any similar-sized package. This package features a unique process in which the silicon chips are soft soldered onto the Direct Copper Bond (DCB) substrate instead of the traditional copper leadframe. The DCB ceramic, the same substrate used in high power modules, not only provides 2500V<sub>rms</sub> isolation but also very low junction-to-case thermal resistance (0.35°C/W).

## Ordering Information

Part	Description
CPC44055ST	SuperSIP Package (13 per tube)

## Pin Configuration & Waveforms



## 1 Specifications

### 1.1 Absolute Maximum Ratings @ 25°C

Symbol	Min	Max	Units
Blocking Voltage	-	800	V <sub>P</sub>
Reverse Input Voltage	-	5	V
Input Control Voltage	-	17	V
Input Power Dissipation <sup>1</sup>	-	225	mW
Total Power Dissipation <sup>2</sup>	-	4.4	W
I <sup>2</sup> t for Fusing (1/2 Sine Wave, 60Hz)	-	200	A <sup>2</sup> s
Isolation Voltage, Input to Output 60 Seconds	-	2500	V <sub>rms</sub>
ESD, Human Body Model	-	4	kV
Operational Temperature	-40	+85	°C
Storage Temperature	-40	+125	°C

<sup>1</sup> Derate linearly 1.33mW / °C.

<sup>2</sup> Free air, no heat sink.

*Absolute maximum ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.*

*Typical values are characteristic of the device at +25°C, and are the result of engineering evaluations. They are provided for information purposes only, and are not part of the manufacturing testing requirements.*

### 1.2 Recommended Operating Conditions

Parameter	Conditions	Symbol	Min.	Typ.	Max.	Units
Input Control Voltage <sup>1</sup>	T <sub>A</sub> =-40°C to 85°C	V <sub>IN</sub>	9	-	16	V

<sup>1</sup> For high-noise environments, or high-frequency operation (>60Hz), or for applications with a high inductive load, use V<sub>IN</sub> ≥ 10V.

### 1.3 Electrical Characteristics @ 25°C

Parameter	Conditions	Symbol	Minimum	Typical	Maximum	Units
<b>Output Characteristics</b>						
Load Current Continuous Continuous	No Heat Sink, V <sub>L</sub> =20-280V <sub>rms</sub> T <sub>C</sub> =25°C	I <sub>L</sub>	0.1	-	5	A <sub>rms</sub>
			0.1	-	40	
Maximum Surge Current	1/2 Sine Wave, 60Hz	I <sub>P</sub>	-	-	150	A
Off-State Leakage Current	V <sub>L</sub> =800V	I <sub>LEAK</sub>	-	-	100	µA <sub>P</sub>
On-State Voltage Drop <sup>1</sup>	I <sub>L</sub> =2A <sub>P</sub>	-	-	0.85	1.1	V <sub>P</sub>
Off-State dV/dt	V <sub>IN</sub> =0V	dV/dt	1000	-	-	V/µs
Switching Speeds Turn-On Turn-Off	V <sub>IN</sub> =10V	t <sub>on</sub>	-	-	0.5	cycles
		t <sub>off</sub>	-	-	0.5	
		-	-	6.8	20	
Zero-Cross Turn-On Voltage	1 <sup>st</sup> half-cycle	-	-	-	5	V
	subsequent half-cycle	-	-	-	-	
Holding Current	-	I <sub>H</sub>	-	-	50	mA
Latching Current	-	I <sub>L</sub>	-	-	75	mA
Operating Frequency <sup>2</sup>	-	-	20	-	500	Hz
Load Power Factor for Guaranteed Turn-On <sup>3</sup>	f=60Hz	PF	0.25	-	-	-
<b>Input Characteristics</b>						
Input Resistor	-	R <sub>IN</sub>	0.9	1	1.1	kΩ
Input Control Voltage to Activate	I <sub>L</sub> =1A Resistive, f=60Hz	V <sub>IN</sub>	-	-	5	V
Input Control Voltage to Deactivate	-	-	0.8	-	-	V
Input Current	V <sub>IN</sub> =10V	I <sub>IN</sub>	7.8	8.8	10.1	mA
Reverse Input Current	V <sub>R</sub> =5V	I <sub>R</sub>	-	-	10	µA
<b>Input/Output Characteristics</b>						
Capacitance, Input-to-Output	V <sub>IO</sub> =0V, f=1MHz	C <sub>IO</sub>	-	-	3	pF

<sup>1</sup> Tested at a peak value equivalent.

<sup>2</sup> Zero-cross first half-cycle @ < 100Hz.

<sup>3</sup> Snubber circuits may be required at low power factors.

## 2 Thermal Characteristics

Parameter	Conditions	Symbol	Rating	Units
Thermal Resistance (Junction to Case)	-	$\theta_{JC}$	0.35	°C/W
Thermal Resistance (Junction to Ambient)	Free Air	$\theta_{JA}$	27	°C/W
Junction Temperature (Operating)	-	$T_J$	-40 to +100	°C

### 2.1 Heat Sink Calculation

Higher load currents are possible by using lower thermal resistance heat sink combinations.

#### Heat Sink Rating

$$\theta_{CA} = \frac{(T_J - T_A)}{P_D} - \theta_{JC}$$

$T_J$  = Junction Temperature (°C),  $T_J \leq 150$  °C \*

$T_A$  = Ambient Temperature (°C)

$\theta_{JC}$  = Thermal Resistance, Junction to Case (°C/W) = 0.35 °C/W

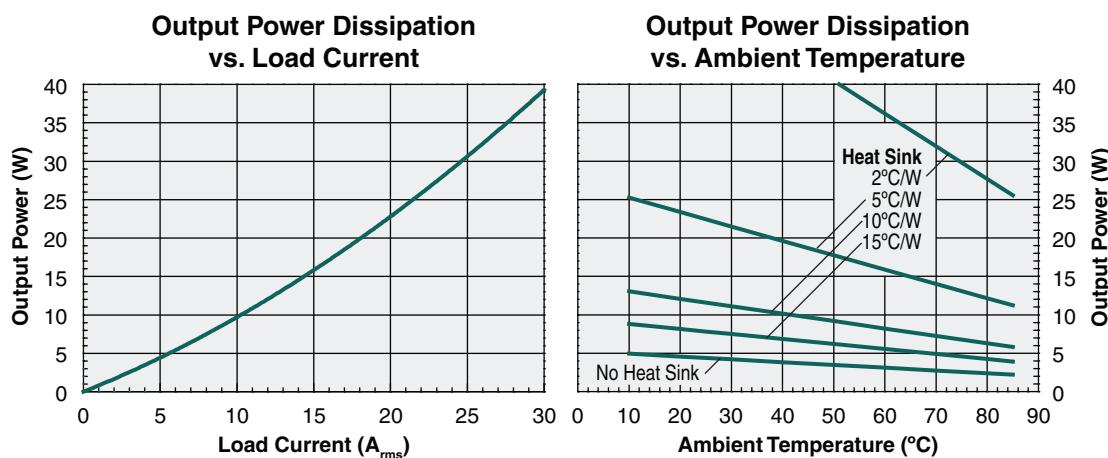
$\theta_{CA}$  = Thermal Resistance of Heat Sink & Thermal Interface Material , Case to Ambient (°C/W)

$P_D$  = On-State Voltage ( $V_{rms}$ ) • Load Current ( $A_{rms}$ )

\* Elevated junction temperature reduces semiconductor lifetime.

**NOTE:** The exposed surface of the DCB substrate is not to be soldered.

### 2.2 Thermal Performance Data



### 3 UL Approved Ratings

#### 3.1 General Loads

Voltage (V <sub>AC</sub> )	Current (A)	Surrounding Air Temperature (°C)
20 - 280	4.75	40
20 - 280	2.5	85
51 - 150	15 (with Heat Sink*)	40
51 - 150	11.75 (with Heat Sink*)	70

#### 3.2 Tungsten Lamp Load

Voltage (V <sub>AC</sub> )	Current (A)	Surrounding Air Temperature (°C)
20 - 280	4.75	40
20 - 280	2.5	85
51 - 150	15 (with Heat Sink*)	40
51 - 150	11.75 (with Heat Sink*)	70

#### 3.3 Motor Load

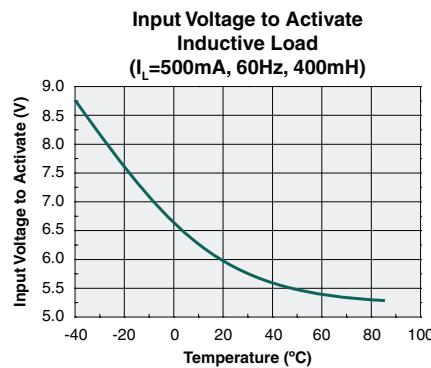
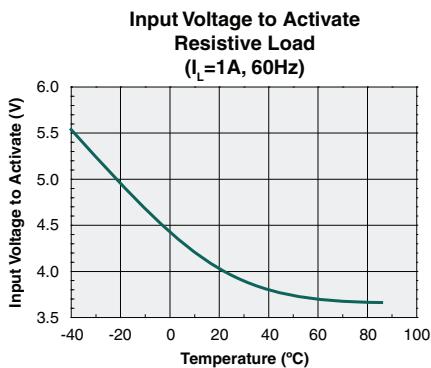
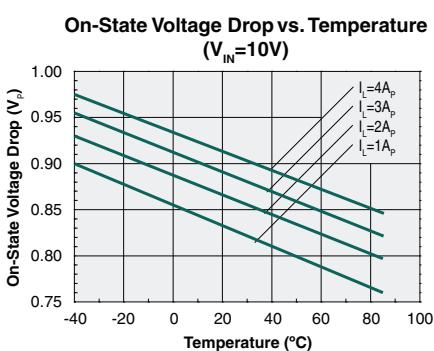
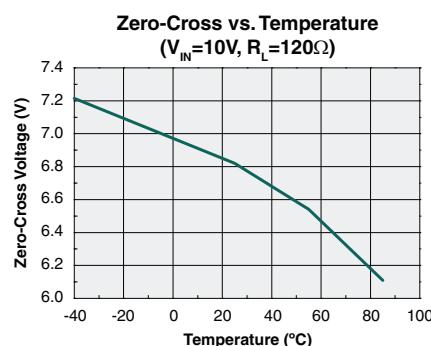
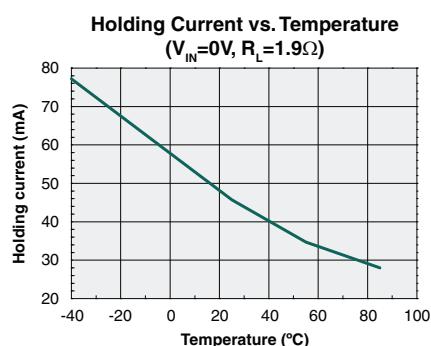
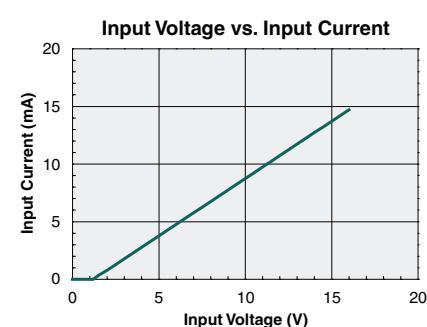
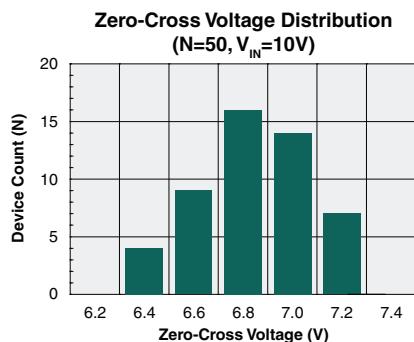
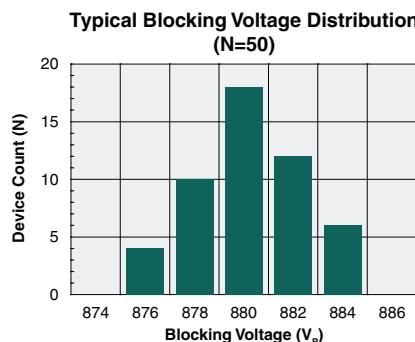
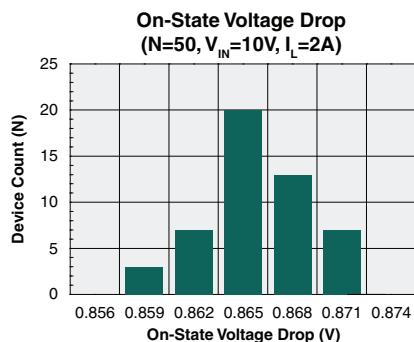
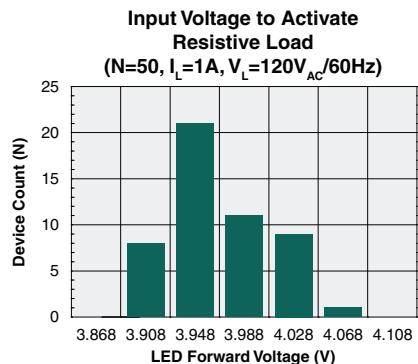
Voltage (V <sub>AC</sub> )	Current	Surrounding Air Temperature (°C)
220 - 240	1/3 HP, 3.6 FLA	40
220 - 240	1/6 HP, 2.2 FLA	85
110 - 120	1/2 HP, 9.8 FLA (with Heat Sink*)	40
110 - 120	1/2 HP, 9.8 FLA (with Heat Sink*)	70

#### 3.4 Electronic Ballast Load

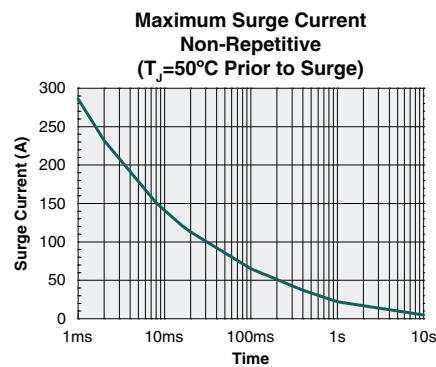
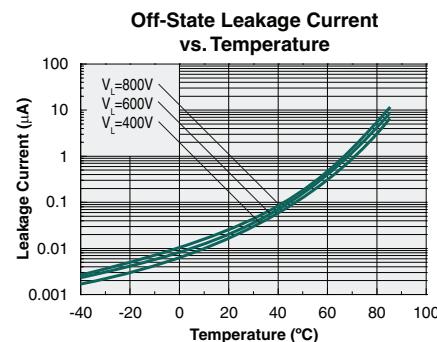
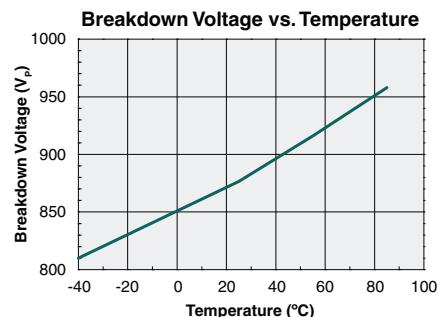
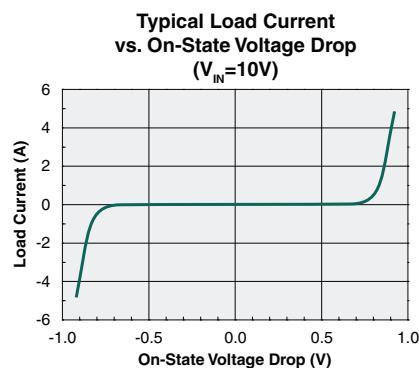
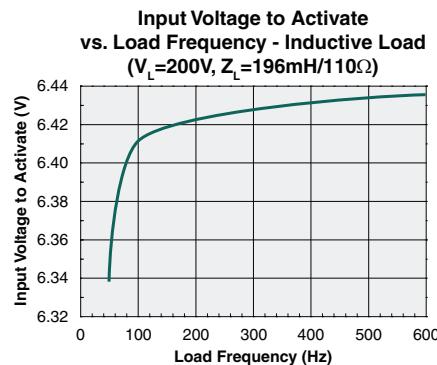
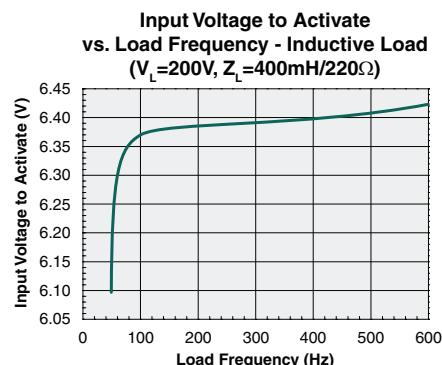
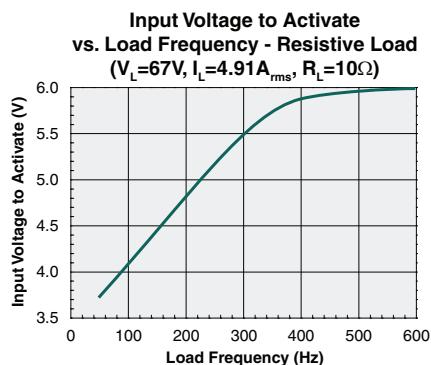
Voltage (V <sub>AC</sub> )	Current (A)	Surrounding Air Temperature (°C)
120	5	35
120	15 (with Heat Sink*)	40
120	10 (with Heat Sink*)	70

**Note:** \*Heat Sink Used for UL Testing: Ohmite MA-302-55E

## 4 Performance Data (@25°C Unless Otherwise Noted)



The performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.



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## 5 Manufacturing Information

### 5.1 Moisture Sensitivity


 All plastic encapsulated semiconductor packages are susceptible to moisture ingress. IXYS Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL) rating** as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Rating
CPC44055ST	MSL 1

### 5.2 ESD Sensitivity


 This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

### 5.3 Soldering Profile

This product has a maximum body temperature and time rating as shown below. All other guidelines of **J-STD-020** must be observed.

Device	Maximum Temperature x Time
CPC44055ST	245°C for 30 seconds

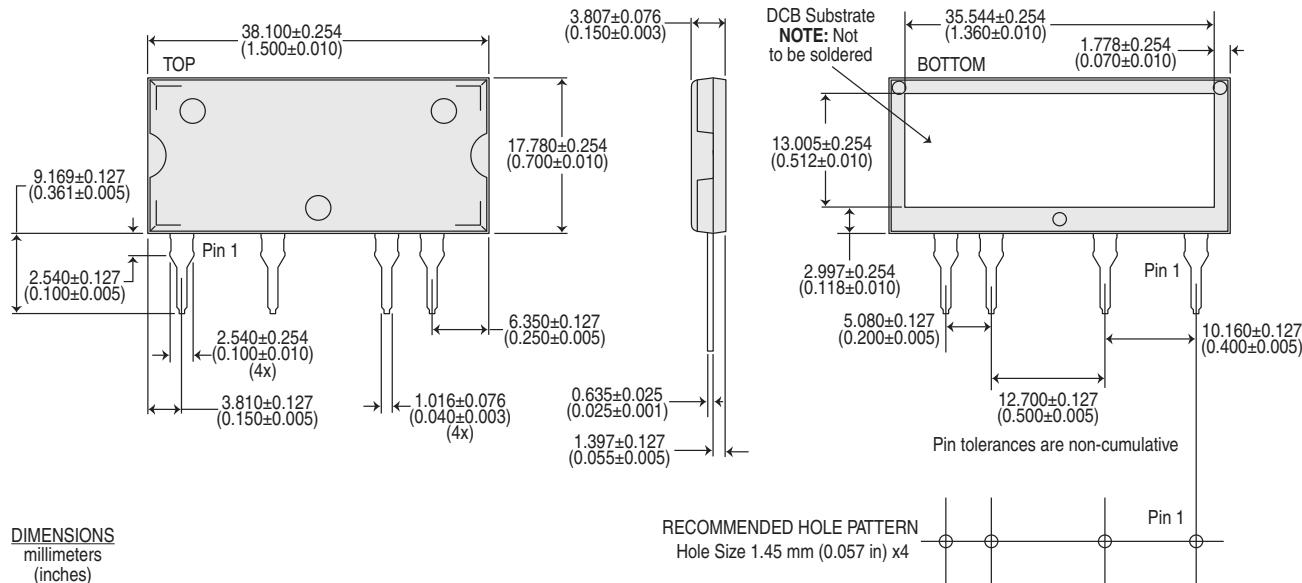
**NOTE:** The exposed surface of the DCB substrate is not to be soldered.

### 5.4 Board Wash

IXYS Integrated Circuits Division recommends the use of no-clean flux formulations. However, board washing to remove flux residue is acceptable. Since IXYS Integrated Circuits Division employs the use of silicone coating as an optical waveguide in many of its optically isolated products, the use of a short drying bake may be necessary if a wash is used after solder reflow processes. Chlorine-based or Fluorine-based solvents or fluxes should not be used. Cleaning methods that employ ultrasonic energy should not be used.



## 5.5 Mechanical Dimensions



For additional information please visit our website at: [www.ixysic.com](http://www.ixysic.com)

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